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(to be used for all correspondence after initial filing)

Total Number of Pages in This Submission

1

Application Number 10/728523

Filing Date 12/2/2003

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Art Unit 1755

Examiner Name Elizabeth Bolden

Attorney Docket Number SP02-251 US

ENCLOSURES (Check all that apply)

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Patentanmeldung Nr. Patent application No. Demande de brevet n°

02292981.4

Der Präsident des Europäischen Patentamts;
Im Auftrag

For the President of the European Patent Office

Le Président de l'Office européen des brevets
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Anmeldung Nr:
Application no.: 02292981.4
Demande no:

Anmeldetag:
Date of filing: 03.12.02
Date de dépôt:

Anmelder/Applicant(s)/Demandeur(s):

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Bezeichnung der Erfindung/Title of the invention/Titre de l'invention:
(Falls die Bezeichnung der Erfindung nicht angegeben ist, siehe Beschreibung.
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Borosilicate glass compositions and uses thereof

In Anspruch genommene Priorität(en) / Priority(ies) claimed /Priorité(s)
revendiquée(s)
Staat/Tag/Aktenzeichen/State/Date/File no./Pays/Date/Numéro de dépôt:

Internationale Patentklassifikation/International Patent Classification/
Classification internationale des brevets:

C03C/

Am Anmeldetag benannte Vertragsstaaten/Contracting states designated at date of
filing/Etats contractants désignées lors du dépôt:

AT BE BG CH CY CZ DE DK EE ES FI FR GB GR IE IT LI LU MC NL
PT SE SI SK TR

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BOROSILICATE GLASS COMPOSITIONS AND USES THEREOF

CROSS-REFERENCE TO RELATED APPLICATION

- [0001] This application is related to copending U.S. utility patent application entitled "A Microfluidic Device and Manufacture Thereof" filed on June 4, 2002 and accorded serial number 10/163,215, which is entirely incorporated herein by reference.

TECHNICAL FIELD

- [0002] The present invention is generally related to glass compositions and, more particularly, is related to borosilicate glass compositions and uses thereof.

BACKGROUND OF THE INVENTION

- [0003] "Pyrex™ like" glass (borosilicate glass) is a well-known glass that has a low coefficient of thermal expansion (CTE) $33 \times 10^{-7}/^{\circ}\text{C}$ and high chemical durability (*i.e.*, resistance to acidic and alkaline reagents). As a result, Pyrex glass has become an important component in many types of laboratory equipment that require chemical durability.
- [0004] However, powdered Pyrex™ glass (frit) is not as important because it undergoes devitrification (*i.e.*, formation of cristobalite, tridymite, and/or quartz crystals that lead to a decrease in glass properties) during sintering at between about 700-800°C. Crystal formation with high CTE lowers the mechanical strength of the sintered glass product. Lower mechanical strength is also due to the volume change associated with the phase transformation from an amorphous state to the crystal state. Thus, when powdered

Pyrex™ glass is used to make frit layers on a substrate having a low CTE, devitrification increases global CTE of the frit layer and thereby causes cracks to form.

[0005] One potential solution to overcome devitrification in powdered Pyrex™ glass is to add an inhibitor oxide such as alumina to the powdered Pyrex™ glass. The addition of the alumina tends to inhibit the formation of high expansion crystals. The addition of alumina, however, causes the sintering ability of the frit glass to decrease. In addition, the fluidity of the frit glass is decreased during sintering when alumina has been added.

[0006] Thus, a heretofore unaddressed need exists in the industry to form a glass frit that addresses the aforementioned deficiencies and/or inadequacies.

SUMMARY OF THE INVENTION

[0007] A representative borosilicate glass includes a borosilicate glass composition. The borosilicate glass composition includes silicon dioxide (SiO_2) in a range from about 60% to 74% by total composition weight; boric oxide (B_2O_3) in a range from about 9% to 25% by total composition weight; aluminum oxide (Al_2O_3) in a range from about 7% to 17% by total composition weight; and at least one alkali oxide in a range from about 2% to 7% by total composition weight. In addition, the borosilicate glass has a coefficient of thermal expansion (CTE) that is in a range between about $30 \times 10^{-7}/^\circ\text{C}$ and $55 \times 10^{-7}/^\circ\text{C}$. Furthermore, the borosilicate glass composition resists devitrification upon sintering without the addition of an inhibitor oxide.

[0008] A representative method of making a borosilicate glass includes forming a homogeneous mixture by mixing a plurality of components. The components of the homogeneous mixture include silicon dioxide (SiO_2) in a range from about 60% to 74% by total composition weight, boric oxide (B_2O_3) in a range from about 9% to 25% by total composition weight, aluminum oxide (Al_2O_3) in a range from about 7% to 17% by total composition weight, and at least one alkali oxide in a range from about 2% to 7% by total composition weight. Next the method includes melting the homogeneous mixture; and sintering the homogeneous mixture forming a borosilicate glass. The borosilicate glass has a coefficient of thermal expansion (CTE) that is in a range between about $30 \times 10^{-7}/^\circ\text{C}$ and $55 \times 10^{-7}/^\circ\text{C}$. In addition, the homogeneous mixture resists devitrification upon sintering without the addition of an inhibitor oxide.

[0009]

A representative microfluidic device includes a first assembly and a second assembly. The first assembly includes a microstructure that is disposed on a first substrate. The second assembly includes a second substrate and a precursor material. The second assembly and the first assembly are positioned such that the precursor material and the microstructure are adjacent one another. The second assembly is positioned on the microstructure after the first assembly is presintered and adhered thereto by heat treatment to form a one-piece microstructure defining at least one recess between the first and second assemblies. The precursor material includes silicon dioxide (SiO_2) in a range from about 60% to 74% by total composition weight; boric oxide (B_2O_3) in a range from about 9% to 25% by total composition weight; aluminum oxide (Al_2O_3) in a range from about 7% to 17% by total composition weight; and at least one alkali oxide in a range from about 2% to 7% by total composition weight. In addition, the precursor material has a coefficient of thermal expansion (CTE) that is in a range between about $30 \times 10^{-7}/^\circ\text{C}$ and $55 \times 10^{-7}/^\circ\text{C}$. Further, the precursor material resists devitrification upon sintering without the addition of an inhibitor oxide.

[0010]

A representative method of fabricating a microfluidic device includes providing a first assembly and a second assembly. The first assembly includes a microstructure that is disposed on a first substrate. The second assembly includes a second substrate and a precursor material. The precursor material includes a borosilicate glass composition that has a coefficient of thermal expansion (CTE) that is in a range between about $30 \times 10^{-7}/^\circ\text{C}$ and $55 \times 10^{-7}/^\circ\text{C}$. In addition, the borosilicate glass composition resists devitrification upon sintering without the addition of an inhibitor oxide. The precursor material includes silicon dioxide (SiO_2) in a range from about 60% to 74% by total composition weight; boric oxide (B_2O_3) in a range from about 9% to 25% by total composition weight; aluminum oxide (Al_2O_3) in a range from about 7% to 17% by total composition weight; and at least one alkali oxide in a range from about 2% to 7% by total composition weight. In addition, the precursor material has a coefficient of thermal expansion (CTE) that is in a range between about $30 \times 10^{-7}/^\circ\text{C}$ and $55 \times 10^{-7}/^\circ\text{C}$. Further, the precursor material resists devitrification upon sintering without the addition of an inhibitor oxide. The method also includes disposing the first assembly on the second assembly such that the precursor material and the microstructure are adjacent one another and heating the first assembly and the second

assembly to form a one-piece microstructure defining at least one recess between the first and second assemblies.

[0011] Other compositions, systems, methods, devices, features, and advantages of the present invention will be or become apparent to one with skill in the art upon examination of the following drawings and detailed description. It is intended that all such additional systems, methods, features, and advantages be included within this description, be within the scope of the present invention, and be protected by the accompanying claims.

BRIEF DESCRIPTION OF THE DRAWINGS

[0012] Many aspects of the invention can be better understood with reference to the following drawings. The components in the drawings are not necessarily to scale, emphasis instead being placed upon clearly illustrating the principles of the present invention. Moreover, in the drawings, like reference numerals designate corresponding parts throughout the several views.

[0013] FIG. 1 is a cross-sectional view that illustrates an exemplary microfluidic device that includes the borosilicate glass composition of the present invention.

[0014] FIGS. 2A' through 2E illustrate cross-sectional views of an exemplary fabrication process of the microfluidic device illustrated in FIG. 1.

DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENT

[0015] Embodiments of the present invention provide for borosilicate glass compositions, methods of preparation thereof, and structures incorporating borosilicate glass formed from the borosilicate glass compositions. Embodiments of the present invention overcome at least some of the aforementioned deficiencies and inadequacies described above by providing borosilicate glass compositions that self-inhibit the formation of detrimental crystals. As discussed above, formation of one or more of these crystals may likely cause an increase in the coefficient of thermal expansion (CTE). Consequently, the glass product loses mechanical strength due, at least in part, to the volume change associated with crystal formation.

- [0016] In addition, the borosilicate glass compositions may be formulated to resist thermal shock, be chemically resistant to acidic and alkaline chemical reagents, and have low softening points, while not devitrifying and causing crystals.
- [0017] In particular, a glass formed from an embodiment of the borosilicate glass composition preferably has a coefficient of thermal expansion (CTE) that is in a range between about $30 \times 10^{-7}/^{\circ}\text{C}$ and $55 \times 10^{-7}/^{\circ}\text{C}$. In addition, the borosilicate glass composition preferably resists devitrification upon sintering without the addition of an inhibitor oxide (*i.e.*, alumina powder), as discussed above, which decreases sintering ability and fluidity of the borosilicate glass composition during sintering.
- [0018] Embodiments of the borosilicate glass composition include, among others, silicon dioxide (SiO_2), boric oxide (B_2O_3), aluminum oxide (Al_2O_3), and at least one alkali oxide. The alkali oxide may preferably include lithium oxide (Li_2O), potassium oxide (K_2O), and sodium oxide (Na_2O). Not intending to be bound by theory, it appears that Al_2O_3 plays a role in inhibiting the formation of cristobalite and tridymite crystals during the sintering of the borosilicate glass composition. In addition, it appears that B_2O_3 increases the meltability of the borosilicate glass composition and acts as an efficient flux without significantly increasing the CTE of the borosilicate glass, while the alkali oxide increases the CTE of the borosilicate glass.
- [0019] It is also possible to add conventional finishing agents such as As_2O_3 or Sb_2O_3 , fluorides, bromides, or chlorides, with the provision that their total content does not exceed approximately 1%. If desired, bleaching agents may be added. It is also possible to color the glass by adding conventional coloring elements.
- [0020] In particular, one embodiment of the borosilicate glass composition includes SiO_2 in a range between about 60% and 74% by total composition weight, B_2O_3 in a range between about 9% and 25% by total composition weight, Al_2O_3 in a range between about 7% and 17% by total composition weight, and the at least one alkali oxide in a range between about 2% and 7% by total composition weight.
- [0021] In addition, the borosilicate glass composition may include one or more alkaline-earth oxides. The alkaline-earth oxides include barium oxide (BaO), strontium oxide (SrO), calcium oxide (CaO), and magnesium (MgO). Furthermore, the borosilicate glass composition may include one or more rare-earth oxides such as, but not limited to, lanthanum oxide (La_2O_3), tantalum oxide (Ta_2O_3), yttrium oxide

(Y_2O_3), and cerium oxide (CeO_2). The sum of the weight percentages of the alkaline-earth oxides and/or the rare-earth oxides is in a range between about 0.1% and 7% by total composition weight. Again, not intending to be bound by theory, it appears the alkaline-earth oxide increases the CTE of a borosilicate glass formed from the borosilicate glass composition.

[0022] Furthermore, the borosilicate glass composition may also include zirconium oxide (ZrO_2) in the range between about 0.1% and 5% by total composition weight. Not intending to be bound by theory, addition of the ZrO_2 to the borosilicate glass composition appears to enhance resistance to alkaline reagents.

[0023] In another embodiment the borosilicate glass composition preferably includes SiO_2 , B_2O_3 , Al_2O_3 , Li_2O , and ZrO_2 . Not intending to be bound by theory, it appears that Na_2O and/or K_2O can increase the likelihood of and extent of devitrification and are therefore not included in this embodiment. In addition, B_2O_3 is included to increase melt ability, stability, and reduce glass viscosity, and Li_2O increases melt ability, lowers glass viscosity, and also increases CTE. In particular, adding Al_2O_3 to the borosilicate glass composition causes substitution of Si^{4+} with Al^{3+} in the atomic glass network. Consequently, Li^+ is strongly bonded to the glass network because of the strong coupling between Li^+ and Al^{3+} , which occurs from a need to maintain electroneutrality at the local atomic level. The strong bond of Li^+ to the glass network enhances the acidic resistance of the borosilicate glass composition. Addition of the ZrO_2 to the borosilicate glass composition appears to enhance alkali resistance.

[0024] This embodiment of the borosilicate glass composition can be used to form a glass that has a CTE in a range between about $30 \times 10^{-7}/^\circ\text{C}$ and $45 \times 10^{-7}/^\circ\text{C}$ upon sintering. The borosilicate glass formed from the borosilicate glass composition has a softening point in a range between about 600 and 1000°C . In addition, the borosilicate glass has a percent weight loss of less than about 10 milligrams/ dm^2 according to the DIN 12116 acid resistance test (*i.e.*, determining the percent weight loss after placing the borosilicate glass in a boiling aqueous solution of hydrochloric acid 6N for 6 hours). Furthermore, the borosilicate glass has a percent weight loss of less than about 250 milligrams/ dm^2 according to the ISO 695 alkali resistance test (*i.e.*, determining the percent weight loss after placing the borosilicate glass in a boiling aqueous solution of mixed alkali for 3 hours).

[0025] In particular, the borosilicate glass composition includes SiO_2 in the range between about 68% and 73% by total composition weight, B_2O_3 in the range between about 13% and 17% by total composition weight, Al_2O_3 in the range between about 8% and 15% by total composition weight, Li_2O in the range between about 2% and 5% by total composition weight, and ZrO_2 in the range between about 1% and 3% by total composition weight. In addition, the sum of the weight percent of SiO_2 , Al_2O_3 , and ZrO_2 in the borosilicate glass composition is less than 78% by total composition weight.

[0026] The method of forming borosilicate glass composition includes forming a homogeneous mixture of the components of the borosilicate glass composition described above. The homogeneous mixture is then melted at a temperature of about $1650 \pm 10^\circ\text{C}$ in a platinum-rhodium crucible or the like, which may take from about 5 to 10 hours. After the homogeneous mixture is melted, the melted composition is quenched into deionized water and then milled in dry conditions using an alumina ball mill or the like into borosilicate frit particles. Then sieved particles are disposed into a mold (*i.e.*, silicon mold) and sintered at a temperature about 20°C above the softening point of the borosilicate glass (*i.e.*, about 850°C) for about 20 to 40 minutes.

[0027] Table 1 includes three (Compositions 1-3) representative borosilicate glass compositions, the PyrexTM glass chemical composition, and two (Compositions A and B) other glass compositions. In addition, glass properties (*e.g.*, bulk glass CTE, softening point, DIN 12116 acid resistance test, and ISO 695 alkali resistance test) and glass powder properties (*e.g.*, sintered glass CTE and crystalline phase) were measured for each composition listed above and are included in Table 1 for comparative purposes. As can be seen from Table 1, Compositions 1-3 have CTE's (sintered glass) and softening points less than the PyrexTM glass compositions. In addition, Compositions 2 and 3 have comparable chemical resistances to that of the PyrexTM chemical compositions. Compositions 1-3 do not form cristobalite crystalline phases, while the PyrexTM chemical compositions and Compositions A and B form cristobalite crystalline phases. Thus, Compositions 1-3 have physical characteristics superior to that of the PyrexTM chemical composition and Compositions A and B.

Table 1

	Comp. 1 (% weight)	Comp. 2 (% weight)	Comp. 3 (% weight)	Pyrex™ (% weight)	Comp. A (% weight)	Comp. B (% weight)
SiO ₂	65	71	71	81	20	74.7
B ₂ O ₃	15	15	15	13	15	13
Al ₂ O ₃	11	10.7	9.7	2	3	9
Li ₂ O	2	3.3	3.3	-	1	3.3
K ₂ O	-	-	-	4	-	-
K ₂ O	2	-	-	-	6	-
B ₂ O	5	-	-	-	5	-
ZrO ₂	-	-	1	-	-	-
Bulk Glass CTE (10 ⁻⁷ /°C)	39.1	34.6	33.8	32.5	40.1	35.6
Sintered Glass CTE (10 ⁻⁷ /°C)	39.7	35	35.2	79.2	12.1	80.6
Softening Point (°C)	790	808	795	823	-	777
DIN 12116 (mg/dm ²)	42	1.7	2.8	20.1	-	0.4
ISO 695 (mg/dm ²)	-	226	153	102	-	113
Crystalline Phases	Amorphous	Amorphous/ Quartz	Amorphous/ Quartz	Cristobalite	Cristobalite	Cristobalite/ Quartz

[0028] In another embodiment of the present invention, the borosilicate glass compositions can be used in microfluidic devices as precursor materials that may enhance the contact between components of the microfluidic device (*i.e.*, a substrate and a microstructure). The borosilicate glass formed from the borosilicate glass composition has a CTE that is compatible with the CTE of the other components of the microfluidic device upon sintering. The compatible CTEs allow fabrication and use without mechanical stresses. In addition, the borosilicate glass composition may be formulated so that the borosilicate glass formed from the borosilicate glass composition is chemically resistant to chemical reagents (*i.e.*, acidic and/or alkaline chemical reagents) that may be used during the operation of the microfluidic device.

[0029] Reference will now be made to the figures. FIG. 1 is a cross-sectional view of a representative microfluidic device 10 that incorporates a borosilicate glass composition

of the present invention. The microfluidic device 10 includes a first substrate 11, a microstructure 13, a precursor material 15, and a second substrate 17. The microstructure 13 is disposed between the first substrate 11 and the precursor material 15. The precursor material 15 is disposed on the second substrate 17 adjacent the microstructure 13.

[0030] The first substrate 11, the microstructure 13, and second substrate 17 can be made of materials such as, but not limited to glasses, glass ceramics, ceramics, metals, semiconductors, or combinations thereof. The first substrate 11, the microstructure 13, and the second substrate 17 can be constructed of the same or of different materials.

[0031] The first substrate 11, the microstructure 13, the precursor material 15, and the second substrate 17 can be combined to form recesses bounded by the microstructure 13 and the precursor material 15. The recesses can have various cross-sectional dimensions such as, but not limited to, substantially square, substantially rectangular, substantially hexagonal, semicircular, or substantially circular. For example, FIG. 1 shows the recesses to be substantially square.

[0032] In addition, the total volume of the recesses can vary depending on the particular application. The degree of perforation (*i.e.*, the empty space between the ridges of the microstructure 13) of the microstructure 13 determines the total volume. The preferred embodiment of the microstructure 13 includes a microstructure that is highly perforated so that the total volume of the recesses is large. For example, the percentage of empty space bounded by the microstructure 13 and the precursor material 15 is typically greater than about 50%. However, lower volume percentages are contemplated and are within the scope of the present invention.

[0033] In particular, the first substrate 11 and the second substrate 17 have a thickness in the range of about 200 μm to about 3 millimeters (mm), and preferable at least 200 μm . The microstructure 13 can have a width in the range of about 100 μm to about 300 μm and a height of up to approximately 800 μm ; the widths of the resulting recesses are in the range of about 50 μm to more than about 1000 μm .

[0034] As depicted in FIG. 1, the walls of the microstructure 13 that form the recesses can have a constant thickness. However, the thickness of the wall may be constant, tapered, flaring, or a combination thereof and can be tailored for a particular application.

[0035] Embodiments of the microfluidic device 10 can include at least one porous structure (*i.e.*, first substrate 11, second substrate 17, and/or a microstructure 13). The porous structure may be used to perform separations within the microfluidic device 10. In addition, a porous structure can be used to affix a catalyst thereto, as discussed below.

[0036] In general, the microfluidic device 10 may include appropriate passages (not shown) for inlet and outlet of one or more fluids that flow within the microfluidic device 10. The inlet/outlet can be formed through the first substrate 11, the second substrate 17, and/or the microstructure 13.

[0037] The precursor material 15 can be made of the borosilicate glass compositions described above. The preferred embodiment of the precursor material 15 includes SiO_2 , B_2O_3 , Al_2O_3 , Li_2O , and ZrO_2 . This composition can be used to form a borosilicate glass that has a CTE in a range between about $30 \times 10^{-7}/^\circ\text{C}$ and $45 \times 10^{-7}/^\circ\text{C}$ upon sintering. In addition, the borosilicate glass formed from the borosilicate glass composition preferably has a softening point in a range between about 600 and 1000°C. Further, the borosilicate glass preferably has a percent weight loss of less than 10 milligrams/dm² according to the DIN 12116 acid resistance test as described above. Furthermore, the borosilicate glass preferably exhibits a percent weight loss of less than 250 milligrams/dm² according to the ISO 695 alkali resistance test as described above.

[0038] In particular, the precursor material 15 includes a borosilicate glass composition having SiO_2 in the range between about 68% and 73% by total composition weight, B_2O_3 in the range between about 13% and 17% by total composition weight, Al_2O_3 in the range between about 8% and 15% by total composition weight, Li_2O in the range between about 2% and 5% by total composition weight, and ZrO_2 in the range between about 1% and 3% by total composition weight. In addition, the sum of the weight percent of SiO_2 , Al_2O_3 , and ZrO_2 in the precursor material 15 is less than about 78% by total composition weight.

[0039] In another embodiment, the precursor material 15 includes an organic medium such as, but not limited to, a thermoplastic medium, a thermosetting medium, or a photopolymerizable medium. The organic medium is added to the precursor material 15 to assist in vacuum molding of the precursor material 15. Subsequently, the organic

medium present in the precursor material 15 is substantially eliminated during pre-sintering and sintering.

[0040] In general, the CTE of the first substrate 11, the microstructure 13, the precursor material 15, and the second substrate 17 are compatible to prevent mechanical stresses in the microfluidic device 10 during fabrication and use. In addition, the materials of the first substrate 11, the microstructure 13, the precursor material 15, and the second substrate 17 can be selected to be chemically resistant to chemical reagents (*i.e.*, acidic and/or alkaline chemical reagents) that may be used during the operation of the microfluidic device 10.

[0041] Within the microfluidic device 10, fluids involved in the experiment/test may come into contact only with surfaces of the microfluidic device 10, which are under complete control. In this regard, the surfaces of the microfluidic device 10 can be modified to be active or passive. For example, the surface can include a catalyst or the surface can be covered with a film (*e.g.*, polysiloxane) to make the surface neutral. In addition, the microfluidic device 10 may include electrical conductors, electrodes, and the like, that may be used as heaters, sensors, and the like.

[0042] For the purposes of illustration only, and without limitation, embodiments of the present invention will be described with particular reference to the below-described fabrication methods. Note that not every step in the process is described with reference to the process described in the figures hereinafter. Therefore, the following fabrication processes is not intended to be an exhaustive list that includes every step required to fabricate the embodiments of the microfluidic devices of the present invention.

[0043] FIGS. 2A' through 2E are cross-sectional views of a representative fabrication of the microfluidic device 10 illustrated in FIG. 1. FIGS. 2A' and 2B' are cross-sectional views of the formation of a first assembly 19, while FIGS. 2A" and 2B" are cross-sectional views of the formation of a second assembly 21.

[0044] FIGS. 2A' and 2B' illustrate the formation (*e.g.*, vacuum molding) of the microstructure 13 on the first substrate 11 to form the first assembly 19. FIGS. 2A" and 2B" illustrate the formation (*e.g.*, vacuum molding) of the precursor material 15 on the second substrate 17 to form the second assembly 21.

[0045] In one embodiment the first assembly 19 and the second assembly 21 can be pre-sintered at about 500°C for about 5 hours prior to the step shown in FIG. 2C. In

particular, the pre-sintering process includes: heating the first assembly 19 and/or the second assembly 21 from about 20°C to about 500°C over the course of about 2 hours, holding the temperature of the first assembly 19 and/or the second assembly 21 for about 1 hour, and reducing the temperature from about 500°C to about 20°C over a 2 hour time period.

[0046] FIGS. 2C and 2D illustrate the combination of the first assembly 19 and the second assembly 21, where the second assembly 21 is disposed on top of the first assembly 19 such that the microstructure 13 is in contact with the precursor material 15. Thereafter, the first assembly 19 and the second assembly 21 are sintered at about 820 °C for about 5 hours to form the microfluidic device 10, as shown in FIG. 2E.

[0047] In particular, the sintering process includes: heating the first assembly 19 and/or the second assembly 21 from about 20°C to about 820°C over the course of about 2 hours, holding the temperature of the first assembly 19 and/or the second assembly 21 for about 20 minutes, reducing the temperature from about 820°C to about 500°C over a 10 minute time period, and reducing the temperature from about 500°C to about 20°C over a 2 hour time period.

[0048] It should be emphasized that the above-described embodiments of the present invention, particularly, any “preferred” embodiments, are merely possible examples of implementations, merely set forth for a clear understanding of the principles of the invention. Many variations and modifications may be made to the above-described embodiment(s) of the invention without departing substantially from the spirit and principles of the invention. All such modifications and variations are intended to be included herein within the scope of this disclosure and the present invention and protected by the following claims.

CLAIMS

1. A borosilicate glass, comprising:
a borosilicate glass composition comprising:
silicon dioxide (SiO_2) in a range from about 60% to 74% by total composition weight;
boric oxide (B_2O_3) in a range from about 9% to 25% by total composition weight;
aluminum oxide (Al_2O_3) in a range from about 7% to 17% by total composition weight; and
at least one alkali oxide in a range from about 2% to 7% by total composition weight,
wherein the borosilicate glass has a coefficient of thermal expansion (CTE) that is in a range between about $30 \times 10^{-7}/^\circ\text{C}$ and $55 \times 10^{-7}/^\circ\text{C}$, and wherein the borosilicate glass composition resists devitrification upon sintering without the addition of an inhibitor oxide.
2. The borosilicate glass of claim 1, wherein the at least one alkali oxide is selected from lithium oxide (Li_2O), potassium oxide (K_2O), and sodium oxide (Na_2O).
3. The borosilicate glass of claim 1 or 2, wherein the borosilicate glass composition further includes :
zirconium oxide (ZrO_2) in the range between about 0.1% and 5% by total composition weight.
4. The borosilicate glass of any one of claims 1 to 3, wherein the borosilicate glass composition further includes :
at least one alkaline-earth oxide; and
at least one rare-earth oxide, wherein the sum of the weight percentage is in the range between 0.1% and 7% by total composition weight.

5. The borosilicate glass of claim 4, wherein the alkaline-earth oxide is selected from at least one of barium oxide (BaO), strontium oxide (SrO), calcium oxide (CaO), and magnesium (MgO), and wherein the rare-earth oxide is selected from at least one of lanthanum oxide (La₂O₃), tantalum oxide (Ta₂O₃), yttrium oxide (Y₂O₃) and cerium oxide (CeO₂).

6. The borosilicate glass of any one of claims 1 to 3, wherein the CTE of the borosilicate glass is in a range from about $30 \times 10^{-7}/^{\circ}\text{C}$ to $45 \times 10^{-7}/^{\circ}\text{C}$, wherein the softening point of the borosilicate glass is in a range between about 600 and 1 000°C, wherein the borosilicate glass has a percent weight loss of less than 10 milligrams/dm² according to an acid resistance test, wherein the borosilicate glass has a percent weight loss of less than 250 milligrams/dm² according to an alkali resistance test, and wherein the borosilicate glass composition comprises :

SiO₂ in the range from about 68% to 73% by total composition weight;

B₂O₃ in the range from about 13% to 17% by total composition weight;

Al₂O₃ in the range from about 8% to 15% by total composition weight;

lithium oxide (Li₂O) in the range from about 2% to 5% by total composition weight; and

zirconium oxide (ZrO₂) in the range from about 1% to 3% by total composition weight, wherein the sum of the weight percent of SiO₂, Al₂O₃, and ZrO₂ is less than 78% by total composition weight.

7. A method of making a borosilicate glass, comprising:
forming a homogeneous mixture by mixing a plurality of components,
comprising:
silicon dioxide (SiO₂) in a range from about 60% to 74% by total composition weight,
boric oxide (B₂O₃) in a range from about 9% to 25% by total composition weight,
aluminum oxide (Al₂O₃) in a range from about 7% to 17% by total composition weight, and

at least one alkali oxide in a range from about 2% to 7% by total composition weight;
 melting the homogeneous mixture; and
 sintering the homogeneous mixture forming a borosilicate glass,
 wherein the borosilicate glass has a coefficient of thermal expansion (CTE) that is in a range between about $30 \times 10^{-7}/^{\circ}\text{C}$ and $55 \times 10^{-7}/^{\circ}\text{C}$, and wherein the homogeneous mixture resists devitrification upon sintering without the addition of an inhibitor oxide.

8. The method of claim 7, wherein forming a homogeneous mixture by mixing a plurality of components further includes:

zirconium oxide (ZrO_2) in the range from about 0.1% to 5% by total composition weight.

9. The method of claim 7 or 8, wherein melting the homogeneous mixture further includes :

melting the homogeneous mixture at about 1650°C .

10. The method of any one of claims 7 to 9, wherein the CTE of the borosilicate glass is in a range from about $30 \times 10^{-7}/^{\circ}\text{C}$ to $45 \times 10^{-7}/^{\circ}\text{C}$, wherein the softening point of the borosilicate glass is in a range between about 600 and 1000°C , wherein the borosilicate glass has a percent weight loss of less than 10 milligrams/ dm^2 according to an acid resistance test, wherein the borosilicate glass has a percent weight loss of less than 250 milligrams/ dm^2 according to an alkali resistance test; and wherein the homogeneous mixture further includes :

SiO_2 in the range from about 68% to 73% by total composition weight;

B_2O_3 in the range from about 13% to 17% by total composition weight;

Al_2O_3 in the range from about 8% to 15% by total composition weight;

lithium oxide (Li_2O) in the range from about 2% to 5% by total composition weight; and

zirconium oxide (ZrO_2) in the range from about 1% to 3% by total composition weight, wherein the sum of the weight percent of SiO_2 , Al_2O_3 , and ZrO_2 is less than 78% by total composition weight.

11. The method of any one of claims 7 to 10, wherein forming a homogeneous mixture by mixing a plurality of components further includes :

at least one alkaline-earth oxide; and

at least one rare-earth oxide, wherein the sum of the weight percentage is in the range from about 0.1% to 7% by total composition weight.

12. The method of claim 11, wherein the alkaline-earth oxide is selected from barium oxide (BaO), strontium oxide (SrO), calcium oxide (CaO), and magnesium (MgO), and wherein the rare-earth oxide is selected from lanthanum oxide (La_2O_3), tantalum oxide (Ta_2O_3), yttrium oxide (Y_2O_3) and cerium oxide (CeO_2).

13. The method of any one of claims 7 to 12, wherein sintering the homogeneous mixture further includes :

sintering the homogeneous mixture at a temperature about 20°C above the softening point of the homogeneous mixture.

14. A microfluidic device, comprising:

a first assembly comprising a microstructure and a first substrate, wherein the microstructure is disposed on the substrate; and

a second assembly comprising a second substrate and a precursor material, wherein the second assembly and the first assembly are positioned such that the precursor material and the microstructure are adjacent one another, wherein the second assembly is positioned on the microstructure after the first assembly is presintered and adhered thereto by heat treatment to form a one-piece microstructure defining at least one recess between the first and second assemblies, wherein the precursor material includes:

silicon dioxide (SiO_2) in a range from about 60% to 74% by total composition weight;

boric oxide (B_2O_3) in a range from about 9% to 25% by total composition weight;

aluminum oxide (Al_2O_3) in a range from about 7% to 17% by total composition weight; and

at least one alkali oxide in a range from about 2% to 7% by total composition weight;

wherein the precursor material has a coefficient of thermal expansion (CTE) that is in a range between about $30 \times 10^{-7}/^\circ\text{C}$ and $55 \times 10^{-7}/^\circ\text{C}$, and wherein the precursor material resists devitrification upon sintering without the addition of an inhibitor oxide.

15. The microfluidic device of claim 14, wherein the precursor material further comprises:

zirconium oxide (ZrO_2) in the range from about 0.1% to 5% by total composition weight.

16. The microfluidic device of claim 14 or 15, wherein the CTE of the precursor material is in a range from about $30 \times 10^{-7}/^\circ\text{C}$ to $45 \times 10^{-7}/^\circ\text{C}$, wherein the softening point of the precursor material is in a range from about 600 to 1000°C, wherein the precursor material has a percent weight loss of less than 10 milligrams/ dm^2 according to an acid resistance test, wherein the precursor material has a percent weight loss of less than 250 milligrams/ dm^2 according to an alkali resistance test, and wherein the precursor material comprises :

SiO_2 in the range from about 68% to 73% by total composition weight;

B_2O_3 in the range from about 13% to 17% by total composition weight;

Al_2O_3 in the range from about 8% to 15% by total composition weight;

lithium oxide (Li_2O) in the range from about 2% to 5% by total composition weight; and

zirconium oxide (ZrO_2) in the range from about 1% to 3% by total

composition weight, wherein the sum of the weight percent of

SiO_2 , Al_2O_3 , and ZrO_2 is less than 78% by total composition weight.

17. The microfluidic device of any one of claims 14 to 16, wherein the precursor material further comprises :

at least one alkaline-earth oxide; and

at least one rare-earth oxide, wherein the sum of the weight percentage is in the range from 0.1% to 7% by total composition weight.

18. The microfluidic device of claim 17, wherein the alkaline-earth oxide is selected from barium oxide (BaO), strontium oxide (SrO), calcium oxide (CaO), and magnesium (MgO), and wherein the rare-earth oxide is selected from lanthanum oxide (La_2O_3), tantalum oxide (Ta_2O_3), yttrium oxide (Y_2O_3) and cerium oxide (CeO_2).

19. A method of fabricating a microfluidic device, comprising:

providing a first assembly comprising a microstructure and a first substrate,

wherein the microstructure is disposed on the substrate;

providing a second assembly comprising a second substrate and a precursor

material wherein the precursor material includes:

silicon dioxide (SiO_2) in a range from about 60% to 74% by total composition weight;

boric oxide (B_2O_3) in a range from about 9% to 25% by total composition weight;

aluminum oxide (Al_2O_3) in a range from about 7% to 17% by total composition weight; and

at least one alkali oxide in a range from about 2% to 7% by total composition weight,

wherein the precursor material has a coefficient of thermal expansion (CTE) that is in a range between about $30 \times 10^{-7}/^\circ\text{C}$ and $55 \times 10^{-7}/^\circ\text{C}$ upon sintering, and wherein the precursor material resists devitrification upon sintering without the addition of an inhibitor oxide;

disposing the first assembly on the second assembly such that the precursor material and the microstructure are adjacent one another; and heating the first assembly and the second assembly to form a one-piece microstructure defining at least one recess between the first and second assemblies.

20. The method of claim 19, wherein providing a second assembly comprising a second substrate and a precursor material wherein the precursor material further comprises:

zirconium oxide (ZrO_2) in the range from about 0.1% to 5% by total composition weight.

21. The method of claim 19 or 20, wherein the CTE of the precursor material is in a range from about $30 \times 10^{-7}/^\circ\text{C}$ to $45 \times 10^{-7}/^\circ\text{C}$, wherein the softening point of the precursor material is in a range from about 600 to 1000°C , wherein the precursor material has a percent weight loss of less than 10 milligrams/ dm^2 according to an acid resistance test, wherein the precursor material has a percent weight loss of less than 250 milligrams/ dm^2 according to an alkali resistance test, and wherein the precursor material comprises :

SiO_2 in the range from about 68% to 73% by total composition weight;

B_2O_3 in the range from about 13% to 17% by total composition weight;

Al_2O_3 in the range from about 8% to 15% by total composition weight;

lithium oxide (Li_2O) in the range from about 2% to 5% by total composition weight; and

zirconium oxide (ZrO_2) in the range from about 1% and 3% by total composition weight, wherein the sum of the weight percent of SiO_2 , Al_2O_3 , and ZrO_2 is less than 78% by total composition weight.

22. The method of any one of claims 19 to 21, wherein providing a second assembly comprising a second substrate and a precursor material wherein the precursor material further comprises :

at least one alkaline-earth oxide; and

at least one rare-earth oxide, wherein the sum of the weight percentage is in the range from 0.1% to 7% by total composition weight.

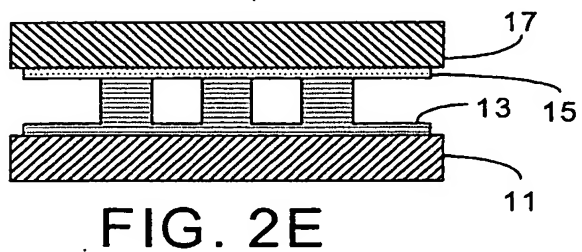
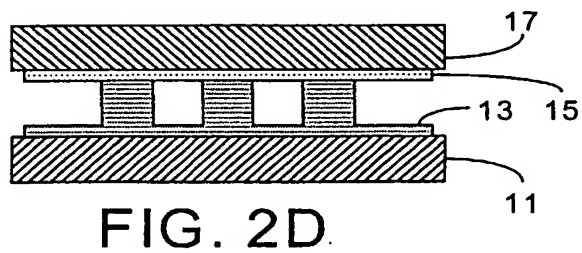
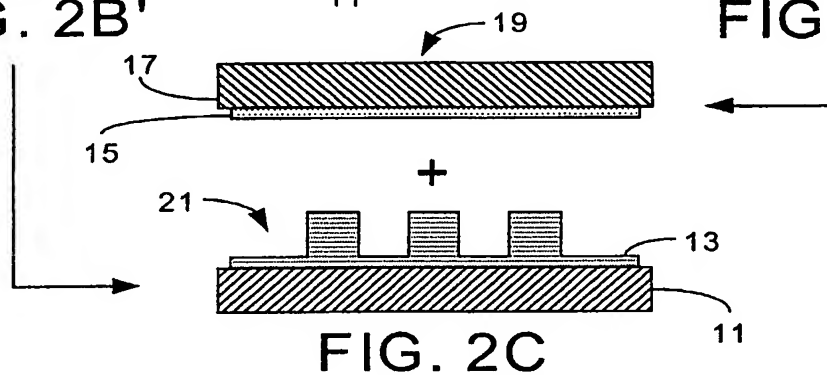
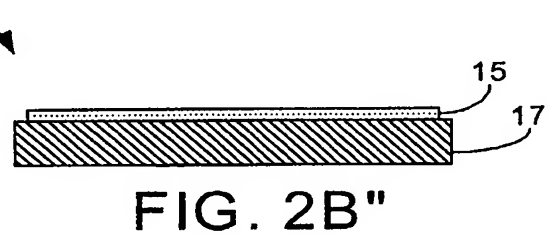
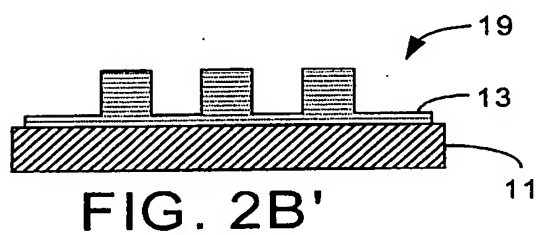
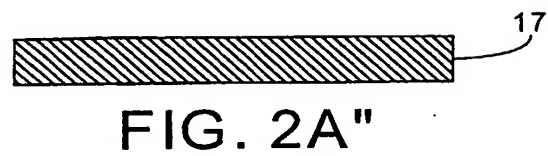
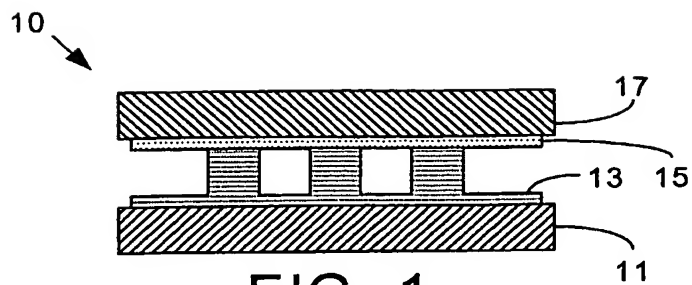
23. The method of claim 22, wherein the alkaline-earth oxide is selected from barium oxide (BaO), strontium oxide (SrO), calcium oxide (CaO), and magnesium (MgO); and wherein the rare-earth oxide is selected from lanthanum oxide (La₂O₃), tantalum oxide (Ta₂O₃), yttrium oxide (Y₂O₃) and cerium oxide (CeO₂).

24. The method of any one of claims 19 to 23, wherein heating the first assembly and the second assembly to form a one-piece microstructure defining at least one recess between the first and second assemblies further comprises :

heating the first assembly and the second assembly at about 820 °C for about 5 hours to form a one-piece microstructure.

ABSTRACT OF THE DISCLOSURE

Glass, glass compositions, methods of preparing the glass compositions, microfluidic devices that include the glass composition, and methods of fabricating microfluidic devices that include the glass composition are disclosed. The borosilicate glass composition includes silicon dioxide (SiO_2) in a range from about 60% to 74% by total composition weight; boric oxide (B_2O_3) in a range from about 9% to 25% by total composition weight; aluminum oxide (Al_2O_3) in a range from about 7% to 17% by total composition weight; and at least one alkali oxide in a range from about 2% to 7% by total composition weight. In addition, the borosilicate glass has a coefficient of thermal expansion (CTE) that is in a range between about $30 \times 10^{-7}/^\circ\text{C}$ and $55 \times 10^{-7}/^\circ\text{C}$. Furthermore, the borosilicate glass composition resists devitrification upon sintering without the addition of an inhibitor oxide.



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